

ZXTN23015CFH 15V, SOT23, NPN medium power transistor

Summary

 $V_{(BR)CEX} > 60V$, $V_{(BR)CEO} > 15V$

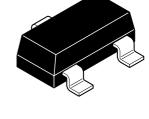
 $I_{C(CONT)} = 6A$

 $R_{CE(SAT)} = 19m\Omega$ typical

 $V_{CE(SAT)} < 30mV @ 1A$

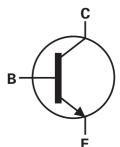
 $P_{D} = 1.25W$

Complementary part number: ZXTP23015CFH



Description

Advanced process capability and package design have been used to maximize the power handling and performance of this small outline transistor. The compact size and ratings of this device make it ideally suited to applications where space is at a premium.



Features

- · Higher power dissipation SOT23 package
- · High peak current
- · Low saturation voltage
- · 60V forward blocking voltage

Applications

- DC DC converters
- · MOSFET and IGBT gate driving
- · Motor drive
- · Relay, lamp, and solenoid drive

C B

Ordering information

Device	Reel size (inches)	Tape width	Quantity per REEL		
ZXTN23015CFHTA	7	8mm	3000		

Device marking

327

Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	V _{CBO}	60	V
Collector-emitter voltage	V _{(BR)CEX}	60	V
Collector-emitter voltage	V _{CEO}	15	V
Emitter-base voltage	V _{EBO}	7.0	V
Peak pulse current	I _{CM}	12	Α
Continuous collector current ^(c)	I _C	6	Α
Base current	I _B	1.2	Α
Power dissipation @ T _A =25°C ^(a) Linear derating factor ^(a)	P _D	0.73 5.84	W mW/°C
Power dissipation @ T _A =25°C ^(b) Linear derating factor ^(b)	P _D	1.05 8.4	W mW/°C
Power dissipation @ T _A =25°C ^(c) Linear derating factor ^(c)	P _D	1.25 9.6	W mW/°C
Power dissipation @ T _A =25°C ^(d) Linear derating factor ^(d)	P _D	1.81 14.5	W mW/°C
Operating and storage temperature	T _j :T _{stg}	-55 to +150	°C

Thermal resistance

Parameter	Symbol	Value	Unit
Junction to ambient ^(a)	$R\Theta_{JA}$	171	°C/W
Junction to ambient ^(b)	$R\Theta_{JA}$	119	°C/W
Junction to ambient ^(c)	$R\Theta_{JA}$	100	°C/W
Junction to ambient ^(d)	$R\Theta_{JA}$	69	°C/W

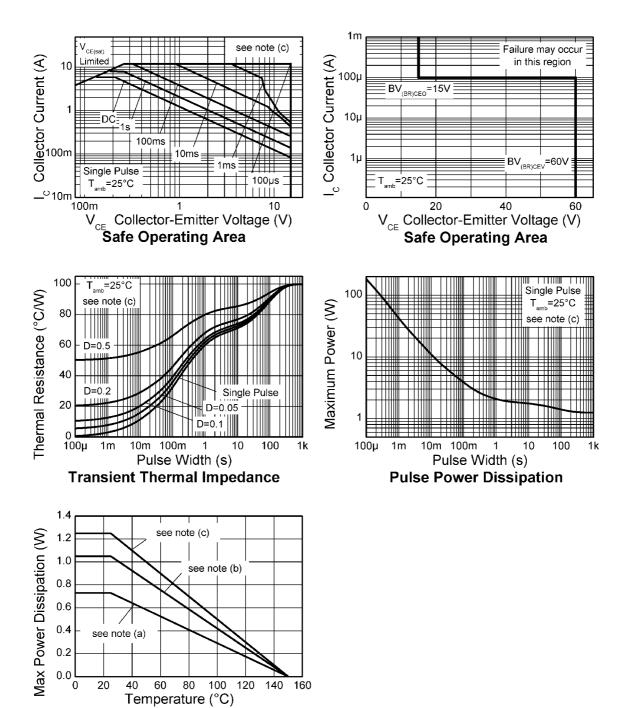
NOTES:

⁽a) For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

⁽b) Mounted on 25mm x 25mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.

⁽c) Mounted on 50mm x 50mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions. (d) As (c) above measured at t<5secs.

Characteristics



Derating Curve

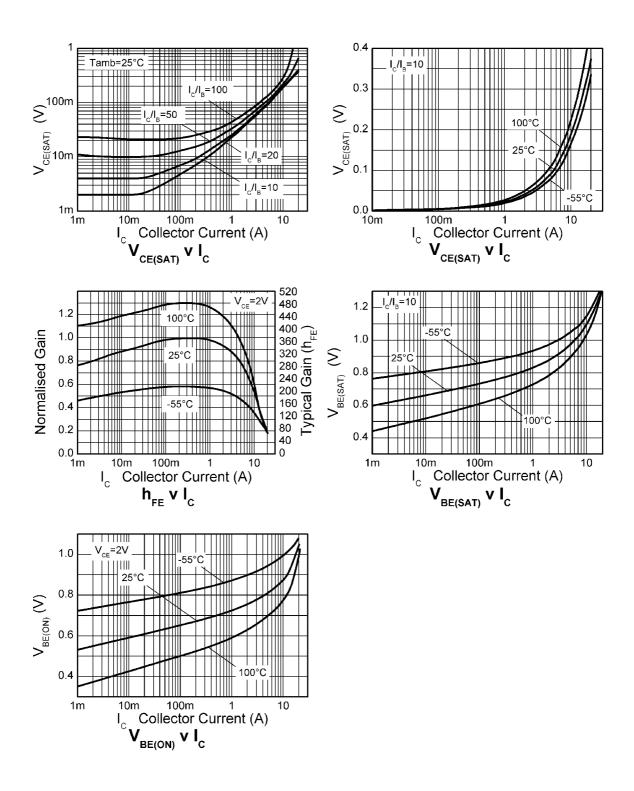
Electrical characteristics (at T_{AMB} = 25°C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	V _{(BR)CBO}	60	85		V	I _C =100μA
Collector-emitter breakdown voltage	V _{(BR)CEX}	60	85		V	$\begin{split} &I_{C} = 100 \mu A, \\ &R_{BE} \leq 1 k \Omega \ \ \textbf{OR} \\ &-1 V < V_{BE} < 0.25 V \end{split}$
Collector-emitter breakdown voltage	V _{(BR)CEO}	15	23		V	I _C =10mA ^(*)
Emitter-base breakdown voltage	$V_{(BR)EBO}$	7.0	8.3		V	I _E =100μA
Collector-emitter cut-off current	I _{CEX}		-	100	nA	$V_{CE} = 48V$, $R_{BE} \le 1k\Omega$ OR $-1V < V_{BE} < 0.25V$
Collector-base cut-off current	I _{CBO}		<1	20	nA	V _{CB} =48V
Emitter-base cut-off current	I _{EBO}		<1	10	nA	V _{EB} =6V
Static forward current transfer	H _{FE}	160	300			I _C =10mA, V _{CE} =2V ^(*)
ratio		200	350	560		I _C =500mA, V _{CE} =2V ^(*)
		190	330			I _C =3A, V _{CE} =2V ^(*)
		150	280			I _C =6A, V _{CE} =2V ^(*)
Collector-emitter saturation	V _{CE(sat)}		7	15	mV	I _C =0.1A, I _B =5mA ^(*)
voltage			22	30	mV	I _C =1A, I _B =100mA ^(*)
			70	90	mV	I _C =3A, I _B =60mA ^(*)
			130	180	mV	I _C =6A, I _B =120mA ^(*)
Base-emitter saturation voltage	V _{BE(sat)}		0.83	0.93	V	I _C =3A, I _B =60mA ^(*)
			0.89	0.98	V	I _C =6A, I _B =120mA ^(*)
Base-emitter turn-on voltage	V _{BE(on)}		0.81	0.91	V	I _C =6A, V _{CE} =2V ^(*)
Transition frequency	f _T		235		MHz	Ic=500mA, V _{CE} =2V, f=50MHz
Output capacitance	C _{obo}		56		pF	V _{CB} =10V, f=1MHz
Delay time	t (d)		15		ns	V _{CC} =5V, I _C =3A,
Rise time	t _(r)		38.5		ns	I _{B1} =I _{B2} =150mA
Storage time	t (stg)		213		ns	
Fall time	t _(f)		19.7		ns	

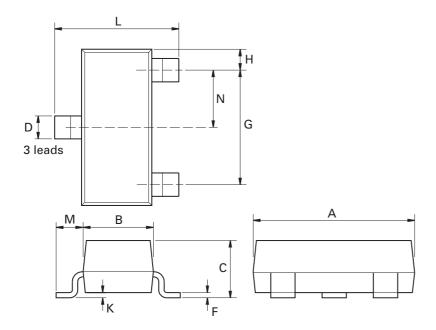
NOTES

(*) Measured under pulsed conditions. Pulse width = 300 μ S. Duty cycle \leq 2%.

Typical characteristics



Package outline - SOT23



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Мах.	Max.
Α	2.67	3.05	0.105	0.120	Н	0.33	0.51	0.013	0.020
В	1.20	1.40	0.047	0.055	K	0.01	0.10	0.0004	0.004
С	-	1.10	-	0.043	L	2.10	2.50	0.083	0.0985
D	0.37	0.53	0.015	0.021	M	0.45	0.64	0.018	0.025
F	0.085	0.15	0.0034	0.0059	N	0.95 NOM		0.0375 NOM	
G	1.90 NOM 0.075 NOM		NOM	-	-	-	-	-	

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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